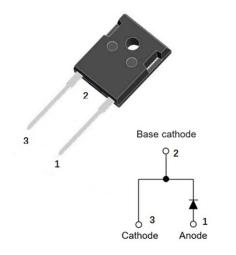


YJD112020NYG5

Silicon Carbide Schottky Diode

V _{RRM}	1200V
I _{F (135°C)}	21A
Q _c	93nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- Package: TO-247AC
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (T_c=25[°]C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D112020NYG5
Reverse voltage (Repetitive peak) @ T _j =25°C	V _{RRM}	V	1200
Reverse voltage (Surge peak) @ T _j =25°C	V _{RSM}	V	1200
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	1200
Continuous forward current @ T_c =25°C		A	45
Continuous forward current @ T_c =135°C	I _F		21
Continuous forward current @ T_c =140°C			20
Non-repetitive peak forward surge current @ T_c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	180
Power Dissipation@ T _c =25°C	Р	W	187
Power Dissipation@ T _c =110°C	P _{TOT}		81
i²t Value@ T _c =25°C ,tp=10ms	∫i²dt	A ² S	162
Operating junction and Storage temperature range	T _j ,T _{stg}	°C	-55 to +175



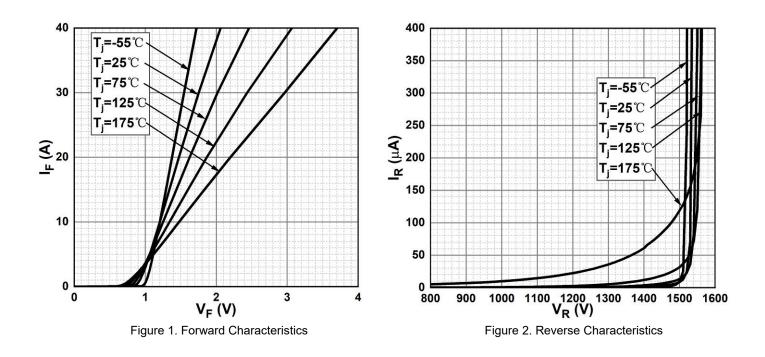
Electrical Characteristics

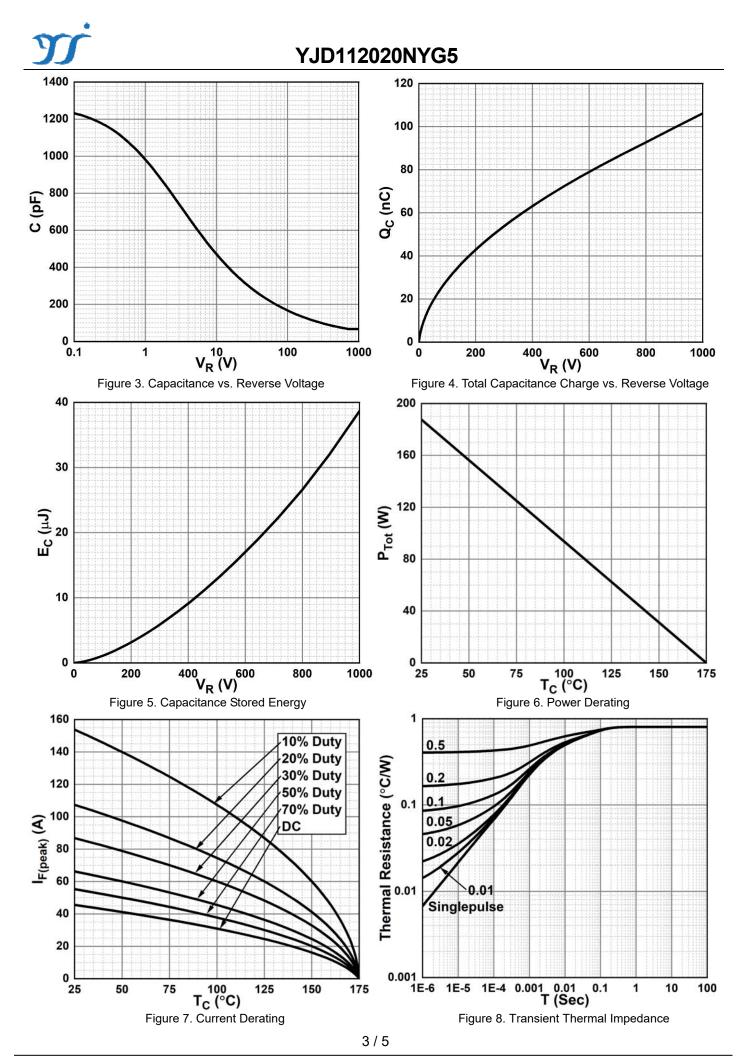
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drag		V	I _F =20A, T _j =25°C	1.48	1.70
Forward voltage drop	V _F		I _F =20A, T _j =175°C	2.2	-
Reverse current		I _R μΑ	V _R =1200V, T _j =25°C	0.5	25
Reverse current	IR		V _R =1200V, T _j =175°C	30	-
Total capacitive charge	Qc	nC	$\begin{array}{l} V_{\text{R}}{=}800\text{V},T_{j}{=}25^{\circ}\text{C}\ ,\\ Q_{\text{C}}{=}{\int_{0}}^{V_{\text{R}}}C(\text{V})\text{dV} \end{array}$	93	-
		pF	V _R =0V, f=1MHZ	1265	-
Total capacitance	С		V _R =400V, f=1MHZ	87	-
			V _R =800V, f=1MHZ	67	-
Capacitance stored energy	Ec	μJ	V _R =800V	26.5	-

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C W	0.80

■Typical Characteristics



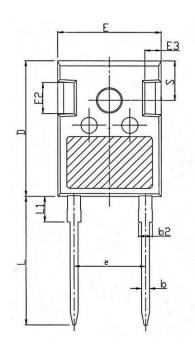


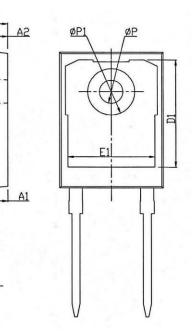
Yangzhou Yangjie Electronic Technology Co., Ltd.



Outline Dimensions

TO-247AC





TO-247AC					
Dim	Min	Max			
А	4.80	5.20			
A1	2.21	2.61			
A2	1.85	2.15			
b	1.11	1.36			
b2	1.91	2.21			
С	0.51	0.75			
D	20.70	21.30			
D1	16.25	16.85			
Е	15.50	16.10			
E1	13.00	13.60			
E2	4.80	5.20			
E3	2.30	2.70			
е	10.88BSC				
L	19.62	20.22			
L1	-	4.30			
ΦР	3.40	3.80			
ΦP1	-	7.30			
S	6.15BSC				

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YJD112020NYG5

Disclaimer

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